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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/590,604	08/24/2006	Andrew Rowser	320529179US1	8963
25996 7590 05/28/2009 PERKINS COIE LLP PATENT-SEA P.O. BOX 1247 SEATTLE, WA 98111-1247				
EXAMINER				
TRAN, CHUC				
ART UNIT		PAPER NUMBER		
2821				
MAIL DATE		DELIVERY MODE		
05/28/2009		PAPER		

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary

Application No.

10/590,604

Applicant(s)

ROWSER ET AL

Examiner

CHUC D. TRAN

Art Unit

2821

Period for Reply -- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 22 December 2008.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-23 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☒ Claim(s) 5, 7, 11, 18 and 23 is/are allowed.
- 6) ☒ Claim(s) 1-4, 6, 8-10, 12-17, 19-22 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- 1) ☐ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO/SF/08)
Paper No(s)/Mail Date _____
- 4) ☐ Interview Summary (PTO-413)
Paper No(s)/Mail Date _____
- 5) ☐ Notice of Informal Patent Application
- 6) ☐ Other: _____

DETAILED ACTION

Response to Arguments

1. Applicant's arguments filed 12/22/08 have been fully considered but they are not persuasive.

Applicant argue in a Remarks page 9 that the reflector plate (20) of the Chien reference is different from the tuned scatter-plate subassembly of the independent claims. The Examiner respectfully disagrees. The reflector plate (20) of Chien reference clearly teach by fine-tuning of the reflector plate may be used in the RF frequency spectrum (Chien, Col.3, Line 62) the same of Applicant's tuned scatter-plate (Applicant, [0017]). Applicants also argue that the "tuned scatter-plate" of claim 1 is intended to receive the signals and focus them onto a receiving antenna. However, these limitations are not recited in the claims. Applicants are reminded that it has been held that limitations from the specification will not be imported or read into the claims. *In re Priest*, 582 F.2d 33, 37, 199 USPQ 11,15 (CCPA 1978).

Claim Rejections - 35 USC § 103

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

3. Claims 1-4, 6, 8-10, 12-17 and 19-22 rejected under 35 U.S.C. 103(a) as being unpatentable over Rowser et al (USP. 6,917,336) in view of Chien (USP. 7,027,005).

Regarding claims 1, 6 and 8, Rowser et al discloses a high gain, broadband, directive, active antenna in Fig. 1-7, comprising: a substantially linear, high-impedance (Abstract),

balanced (impedance matching) (Col. 3, Line 22), differential voltage amplifier (Fig. 6, 7) subassembly utilizing passive lossless feedback for gain scalability (Col. 7, Line 18-36), high linearity (Col. 7, Line 6), and elevated input impedance (Col. 6, Line 26); a pair of dipole probe elements (5) (Col. 2, line 60) subassembly connected to the amplifier (Col. 7, Line 33) (Fig. 6) for producing an electric field sensing transduction mechanism (Col. 3, Line 19) and RF spectrum (Col. 3, Line 54). However, Rowser et al is silent on the limitation of a tuned scatter-plate subassembly (reflector). Chien disclose an RF broadband antenna device in Fig. 2 comprising a tuned scatter-plate subassembly (reflection plate) (20) (Fig. 2). Thus, it would have been obvious to one of ordinary skill in the art to modify Rowser's RF antenna device by adding the tuned scatter-plate subassembly (reflector) as taught by Chien. Adding the tuned scatter-plate subassembly (reflector) for boosting directional frequency gain in order to provide the antenna to achieve higher gain of Rowser et al would have been obvious to one of ordinary skill.

Regarding claims 9 and 12-13, Rowser et al discloses a broadband directive antenna in Fig. 1-7, comprising: a substantially linear, high-impedance (Abstract), balanced (impedance matching) (Col. 3, Line 22), differential voltage amplifier (Fig. 6, 7) subassembly utilizing passive lossless feedback (Abstract), a dipole probe elements (5) (Col. 2, line 60) subassembly connected to the amplifier (Col. 7, Line 33) (Fig. 6) for producing an electric field sensing transduction mechanism (Col. 3, Line 19), and RF spectrum (Col. 3, Line 54) However, Rowser et al is silent on the limitation of a tuned scatter-plate subassembly (reflector). Chien disclose an RF broadband antenna device in Fig. 2 comprising a tuned scatter-plate subassembly (reflection plate) (20) (Fig. 2). Thus, it would have been obvious to one of ordinary skill in the art to modify Rowser's RF antenna device by adding the tuned scatter-plate subassembly (reflector) as taught

by Chien. Adding the tuned scatter-plate subassembly (reflector) for boosting directional frequency gain in order to provide the antenna to achieve higher gain of Rowser et al would have been obvious to one of ordinary skill.

Regarding claims 14 and 16, Rowser et al disclose high gain, broadband, directive, active antenna in Fig. 1-7, comprising: means (voltage amplifying stage) for amplifying signals received by probing means (5) (Col. 5, Line 17), wherein the amplifying means is substantially linear (DC voltage) (Fig. 6), balanced (impedance matching) (Col. 3, Line 22), and high-impedance (Col. 6, Line 3); means (e-field probe) for probing radio frequency signals (Col. 3, Line 19), wherein the probing means is connected to the amplifying means (Col. 7, Line 30-36) (Fig. 6). However, Rowser et al is silent on the limitation of means (reflection plate) for creating directivity with separate frequency-dependant, directive modes. Chien disclose an RF broadband antenna device in Fig. 2 comprising means (reflection plate) (20) (Fig. 2) for creating directivity with separate frequency-dependant, directive modes (reflective) See (Chien, Col. 3, Line 37 and 60). Thus, it would have been obvious to one of ordinary skill in the art to modify Rowser's RF antenna device by adding the reflection plate as taught by Chien. Adding means (reflection plate) for boosting directional frequency gain in order to provide the antenna to achieve higher gain of Rowser et al would have been obvious to one of ordinary skill.

Regarding claims 2, 15 and 21, Rowser et al disclose that a wire-wound transformer (T) connected to a Field Effect Transistor (FET) (Fig. 6), and wherein the voltage amplifier gain is scaled by the transformer turn-ratio (Col. 6, Line 62).

Regarding claim 4, Rowser et al disclose that the inductance (resistance and capacitance) value of the decoupling inductor is such that an RF voltage peaking effect is obtained at a

transistor input (high impedance input) at a desired frequency (Col. 6, Line 3) and (Abstract).

Regarding claims 19-20, Rowser et al disclose an active antenna in Fig. 1-7, comprising: a substantially linear, high-impedance (Abstract), balanced (impedance matching) (Col. 3, Line 22), differential voltage amplifier (Fig. 6, 7) subassembly utilizing passive lossless feedback for gain scalability (Col. 7, Line 18-36), a pair of dipole probe elements (5) (Col. 2, line 60) connected to the amplifier (Col. 7, Line 33) (Fig. 6) for producing an electric field sensing transduction mechanism (Col. 3, Line 19) and RF spectrum (Col. 3, Line 54). However, Rowser et al is silent on the limitation of a bi-directive reception pattern (reflection plate). Chien disclose an RF broadband antenna device in Fig. 2 comprising a bi-directive reception pattern (reflection plate) (20) (Fig. 2). Thus, it would have been obvious to one of ordinary skill in the art to modify Rowser's RF antenna device by adding the tuned scatter-plate subassembly (reflector) as taught by Chien. Adding the tuned scatter-plate subassembly (reflector) for boosting directional frequency gain in order to provide the antenna to achieve higher gain of Rowser et al would have been obvious to one of ordinary skill.

3. Claim 3, 10, 17 and 22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Rowser et al (USP. 6,917,336) in view of Chien (USP. 7,027,005) and further in view of Colman et al (USP. 5,050,236).

Regarding claims 3, 10, 17 and 22, Rowser et al disclose the RF broadband antenna device comprising a bias resistance for reducing noise contribute to the antenna amplifier (Col. 2, Line 50) as set forth in the claims except a bias inductor. Colman et al disclose RF communication device in Fig. 2, comprising a bias inductor (201) (Col. 2, Line 54). Thus, it would have been obvious to one of ordinary skill in the art to modify Rowser's RF antenna

device by providing the bias inductor as taught by Colman et al. Providing the bias inductor for tuning the impedance in order to provide the antenna to achieve higher gain of Rowser et al would have been obvious to one of ordinary skill.

Conclusion

4. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Inquiry

Any inquiry concerning this communication or earlier communications from the examiner should be directed to CHUC D. TRAN whose telephone number is (571)272-1829. The examiner can normally be reached on M-F Flex hours.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Douglas W. Owens can be reached on (571) 272-1662. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Chuc D Tran/
Examiner, Art Unit 2821

/Douglas W Owens/
Supervisory Patent Examiner, Art Unit 2821
May 22, 2009